

Form PTO-1449

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## U.S. PATENT DOCUMENTS

*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
A.M	AA	5,703,404	12/97	Matsuura	257	758	
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

## FOREIGN PATENT DOCUMENTS

		Document Number	Date	Country	Class	Subclass	Translation	
							Yes	No
	AL							
	AM							
	AN							
	AO							
	AP							

## OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

A.M	AR		ARTICLE: Patrick, W., et. al., "Properties of PECVD O <sub>2</sub> /TEOS Silicon Dioxide", Proceedings VLSI Science & Tech. 1991, pp. 692-711.
	AS		
	AT		

EXAMINER

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